

# MA3X557 (MA557)

## Silicon epitaxial planar type

For UHF and SHF bands AGC

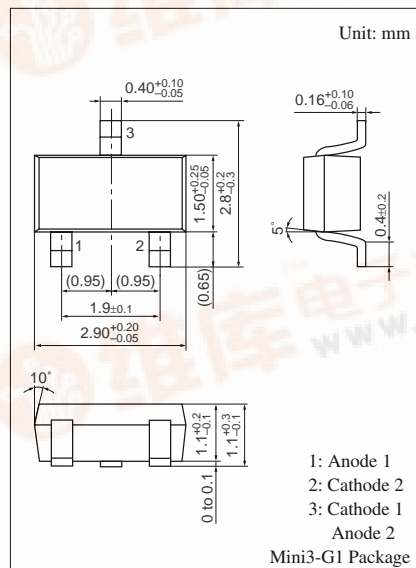
### ■ Features

- Small diode capacitance  $C_D$
- Large variable range of forward dynamic resistance  $r_f$
- Mini type package, allowing downsizing of equipment and automatic insertion through the taping package and magazine package

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

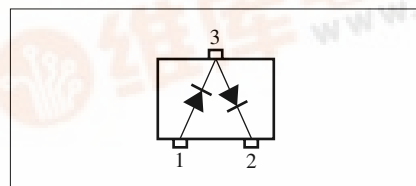
| Parameter                       | Symbol    | Rating      | Unit             |
|---------------------------------|-----------|-------------|------------------|
| Reverse voltage (DC)            | $V_R$     | 40          | V                |
| Peak reverse voltage            | $V_{RM}$  | 45          | V                |
| Forward current (DC)            | $I_F$     | 100         | mA               |
| Power dissipation               | $P_D$     | 150         | mW               |
| Operating ambient temperature * | $T_{opr}$ | -25 to +85  | $^\circ\text{C}$ |
| Storage temperature             | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$ |

Note) \*: Maximum ambient temperature during operation



Marking Symbol: M30

Internal Connection



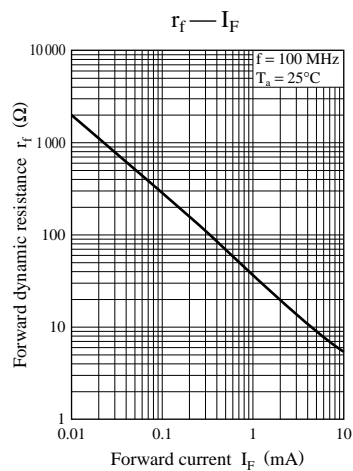
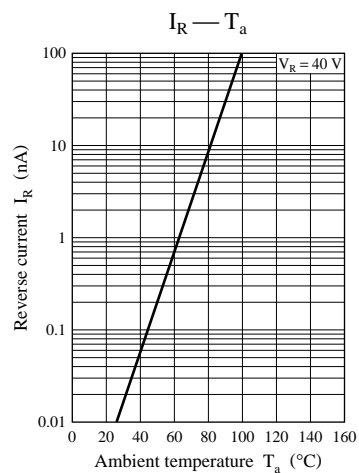
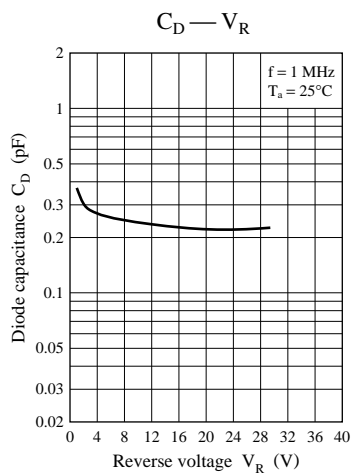
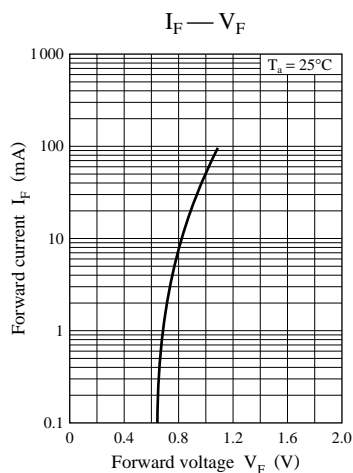
### ■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter                    | Symbol   | Conditions   | Min | Typ  | Max | Unit       |
|------------------------------|----------|--|-----|------|-----|------------|
| Reverse current (DC)         | $I_R$    | $V_R = 40\text{ V}$                                  |     |      | 100 | nA         |
| Forward voltage (DC)         | $V_F$    | $I_F = 100\text{ mA}$                                |     | 1.05 | 1.2 | V          |
| Diode capacitance            | $C_D$    | $V_R = 15\text{ V}$ , $f = 1\text{ MHz}$             |     | 0.3  | 0.5 | pF         |
| Forward dynamic resistance * | $r_{f1}$ | $I_F = 10\text{ }\mu\text{A}$ , $f = 100\text{ MHz}$ | 1   | 2    |     | k $\Omega$ |
|                              | $r_{f2}$ | $I_F = 10\text{ mA}$ , $f = 100\text{ MHz}$          |     | 6    | 10  | $\Omega$   |

Note) 1. Rated input/output frequency: 100 MHz

2. Each characteristic is a standard for individual diode

3. \*: Measuring instrument; YHP MODEL 4191A RF IMPEDANCE ANALYZER



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